imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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V _{CES}	650V
I _{C(100°C)}	25A
V _{CE(sat) (Typ.)}	1.6V
PD	174W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating ; RoHS Compliant

Applications

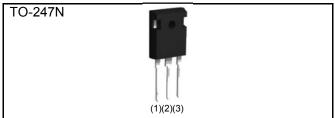
PFC

UPS

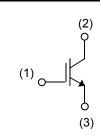
Power Conditioner

IH

Outline



Inner Circuit





Packaging Specifications

Туре	Packaging	Tube
	Reel Size (mm)	-
	Tape Width (mm)	-
	Basic Ordering Unit (pcs)	450
	Packing code	C11
	Marking	RGTH50TS65

•Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Collector - Emitter Voltage	V _{CES}	650	V	
Gate - Emitter Voltage	V _{GES}	±30	V	
Collector Current	T _C = 25°C	Ι _C	50	А
Collector Current	T _C = 100°C	Ι _C	25	А
Pulsed Collector Current	I _{CP} ^{*1}	100	А	
$T_c = 25^{\circ}C$		P _D	174	W
Power Dissipation	T _C = 100°C	P _D	87	W
Operating Junction Temperatur	Tj	-40 to +175	°C	
Storage Temperature	T _{stg}	–55 to +175	°C	

*1 Pulse width limited by T_{imax.}

Thermal Resistance

Parameter	Symbol	Values			Unit
Faranielei	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.86	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Faranielei	Symbol Conditions -		Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV _{CES}	I _C = 10μΑ, V _{GE} = 0V	650	-	-	V
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	-	-	10	μA
Gate - Emitter Leakage Current	I _{GES}	V_{GE} = ±30V, V_{CE} = 0V	-	-	±200	nA
Gate - Emitter Threshold Voltage	V _{GE(th)}	V _{CE} = 5V, I _C = 17.5mA	4.5	5.5	6.5	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	I _C = 25A, V _{GE} = 15V T _j = 25°C T _j = 175°C	-	1.6 2.1	2.1 -	V

•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Deveneter	Quine had	Conditions	Values				
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit	
Input Capacitance	C _{ies}	V _{CE} = 30V	-	1410	-		
Output Capacitance	C _{oes}	V _{GE} = 0V	-	57	-	pF	
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	22	-		
Total Gate Charge	Q_g	V _{CE} = 300V	-	49	-		
Gate - Emitter Charge	Q_{ge}	I _C = 25A	-	15	-	nC	
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	19	-		
Turn - on Delay Time	t _{d(on)}	I _C = 25A, V _{CC} = 400V	-	27	-		
Rise Time	t _r	V _{GE} = 15V, R _G = 10Ω	-	38	-	20	
Turn - off Delay Time	$t_{d(off)}$	T _j = 25°C	-	94	-	ns	
Fall Time	t _f	Inductive Load	-	50	-		
Turn - on Delay Time	t _{d(on)}	I _C = 25A, V _{CC} = 400V	-	27	-		
Rise Time	t _r	V _{GE} = 15V, R _G = 10Ω	-	38	-	20	
Turn - off Delay Time	$t_{d(off)}$	T _j = 175°C	-	107	-	ns	
Fall Time	t _f	Inductive Load	-	65	-		
		I _C = 100A, V _{CC} = 520V					
Reverse Bias Safe Operating Area RBS0		V _P = 650V, V _{GE} = 15V	FULL SQUARE		-		
		R _G = 60Ω, T _j = 175°C					

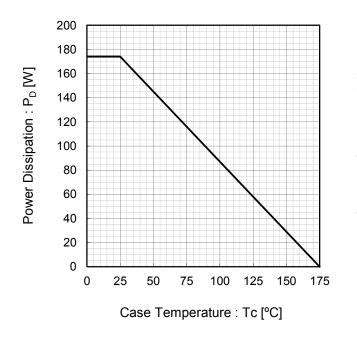


Fig.1 Power Dissipation vs. Case Temperature

Fig.2 Collector Current vs. Case Temperature

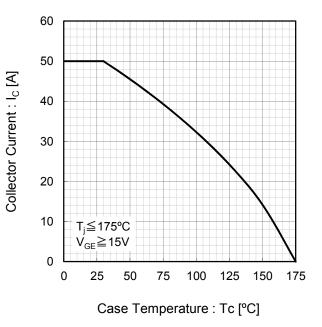
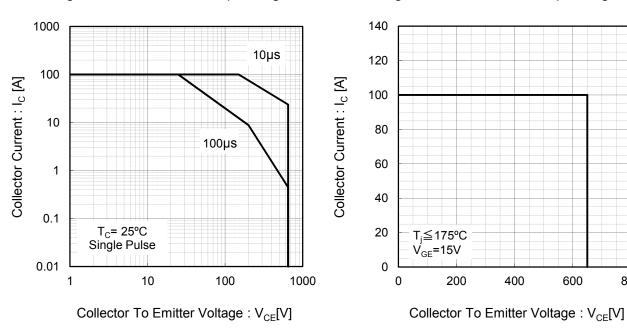


Fig.3 Forward Bias Safe Operating Area

Fig.4 Reverse Bias Safe Operating Area



600

800

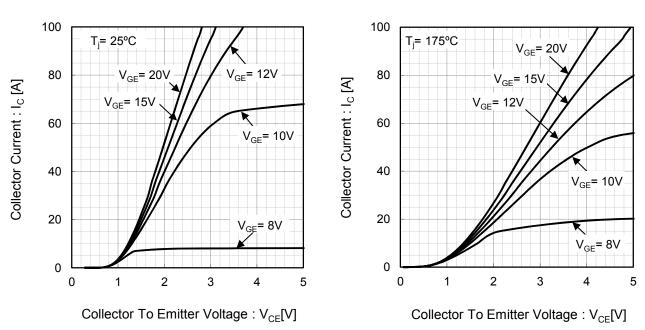
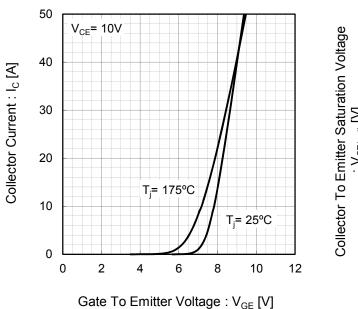


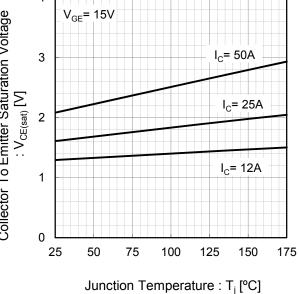
Fig.5 Typical Output Characteristics

Fig.7 Typical Transfer Characteristics

Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

Fig.6 Typical Output Characteristics





T_i= 175°C

20

Electrical Characteristic Curves

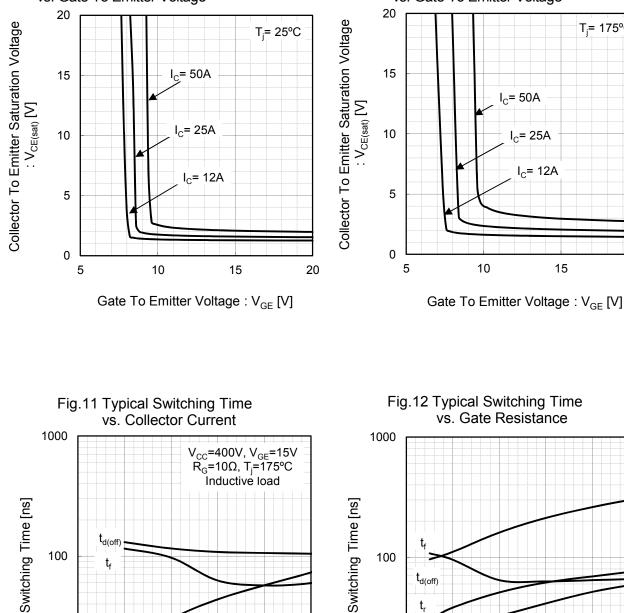
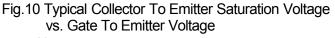


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



t_{d(on)}

t

10

20

Collector Current : I_C [A]

30

40

50

10

0

V_{CC}=400V, I_C=25A V_{GE}=15V, T_j=175°C

Inductive load

40

50

30

Gate Resistance : $R_G[\Omega]$

t.

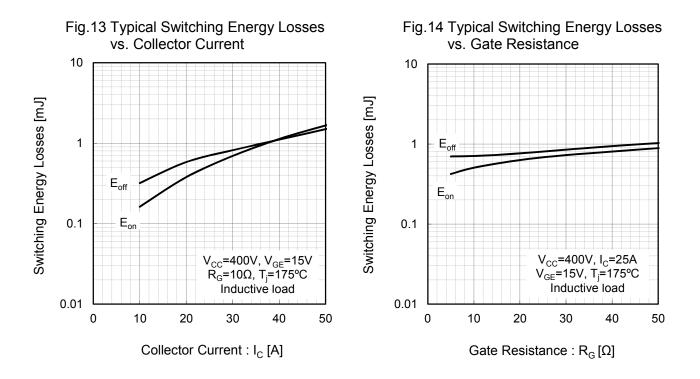
t_{d(on)}

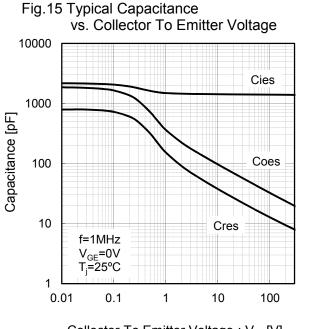
10

20

10

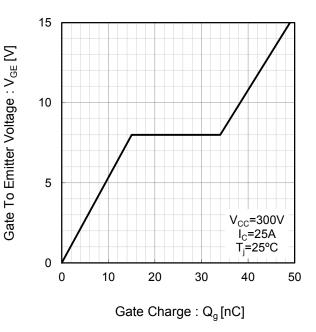
0





Collector To Emitter Voltage : V_{CE}[V]

Fig.16 Typical Gate Charge



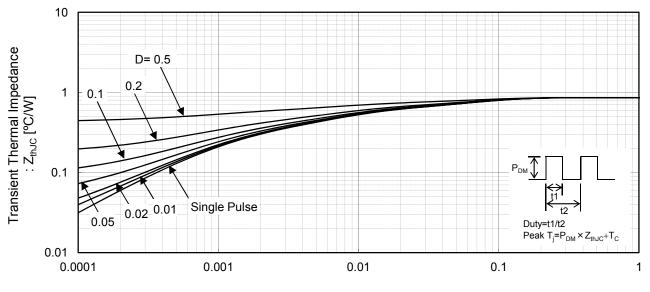


Fig.17 IGBT Transient Thermal Impedance

Pulse Width : t1[s]

●Inductive Load Switching Circuit and Waveform

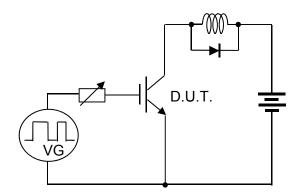
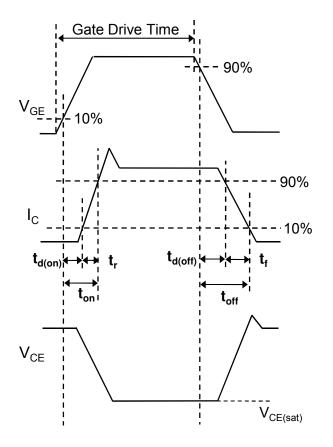


Fig.18 Inductive Load Circuit





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RGTH50TS65 - Web Page

Distribution Inventory

Part Number	RGTH50TS65
Package	TO-247N
Unit Quantity	450
Minimum Package Quantity	450
Packing Type	Bulk
Constitution Materials List	inquiry
RoHS	Yes